

Supporting Information

Interface Reacted ZnFe_2O_4 on $\alpha\text{-Fe}_2\text{O}_3$ Nanoarrays for Largely Improved Photoelectrochemical Activity

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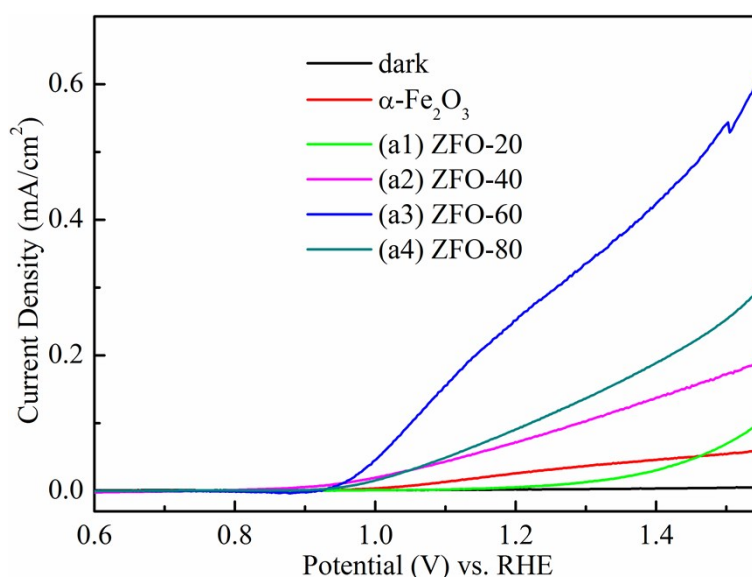


Fig. S1 Variation of Photocurrent density vs bias potential (vs. RHE) (J - V) with different thickness of ZnO layer under AM 1.5 G illumination and in the dark. (a1) 20 nm, (a2) 40 nm, (a3) 60 nm, (a4) 80 nm.

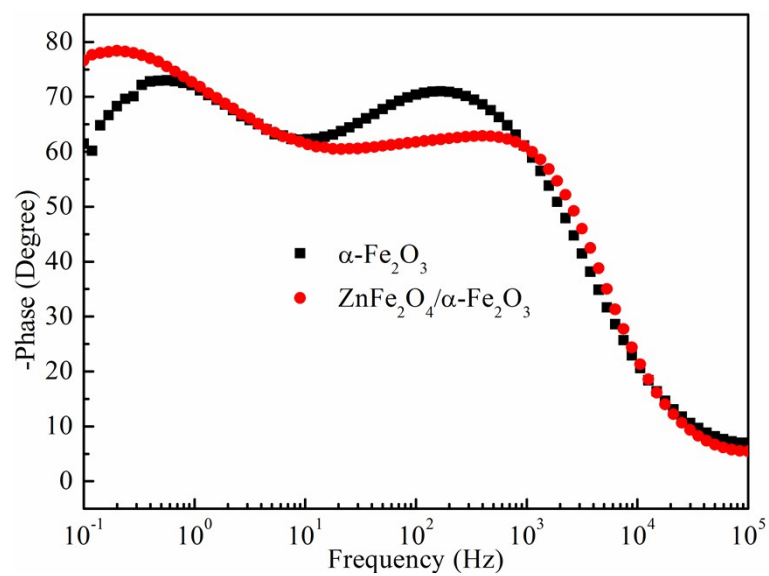


Fig. S2 Bode phase plots of pristine $\alpha\text{-Fe}_2\text{O}_3$ nanorod arrays and $\text{ZnFe}_2\text{O}_4/\alpha\text{-Fe}_2\text{O}_3$ composite nanorod arrays under light.

Table S1 The comparative PEC performances of our work with other previous reports on ZnFe₂O₄/Fe₂O₃. The photocurrent densities were all measured at 1.23 V vs RHE.

| Reference | Photocurrent Density (mA cm ⁻²) | | Enhancement (%) |
|-----------|---|--|-----------------|
| | Fe ₂ O ₃ | ZnFe ₂ O ₄ /Fe ₂ O ₃ | |
| 16 | 0.009 | 0.05 | 456 |
| 11 | 0.18 | 0.23 | 28 |
| 20 | 0.25 | 0.45 | 80 |
| Our Work | 0.03 | 0.28 | 833 |